Electric field, mobility an trapping in Si detectors irradiated with neutrons and protons up to 10¹⁷ n_{or} **C**m⁴

<u>M.Mikuž</u>, G.Kramberger, V.Cindro, I.Mandić, M.Zavrtanik



University of Ljubljana & Jožef Stefan Institute

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Why the 10¹⁷ Ballpark ?

• Run1 at LHC finished, 2 under way

- LHC trackers designed for 730 fb⁻¹ of 14 TeV pp collisions, ~35 fb⁻¹ up to now
- Will probably get ~½ of planned
- HL-LHC in advanced planning
 - 3000 fb⁻¹ i.e. ~10xLHC
 - ~10¹⁵ n_{eq}/cm² for strips (neutrons&pions)
 - ~10¹⁶ n_{eq}/cm² for pixels (pions)
 - nx10¹⁶ n_{eq} /cm² for vFW pixels ($\pi \& n$)
 - ~10¹⁷ n_{eq}/cm² for FCAL (neutrons)
- Can (tracking) sensors survive in these extreme environments ?



1 MeV neutron equivalent fluence



ATLAS FCAL





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- 2 mA for 300 μm thick 1 cm² detector @ -20°C
- Depletion: $N_{eff} \approx 1.5 \times 10^{15} \text{ cm}^{-3}$
 - *FDV* ≈ 100 kV
- Trapping $\tau_{eff} \approx 1/40$ ns = 25 ps
 - $Q \approx Q_0/d v_{sat} \tau_{eff} \approx 80 \text{ e/}\mu\text{m} 200 \ \mu\text{m/ns} 1/40 \text{ ns} = 400 \text{ e} \text{ in very high}$ electric field (>>1 V/ μ m)

Observed signal not at all compatible with expectations



From:

G. Kramberger et al., JINST 8 P08004 (2013).



Edge TCT

• Edge-TCT

- Generate charges by edge-on IR laser perpendicular to strips, detector edge polished
- Focus laser under the strip to be measured, move detector to scan
- Measure induced signal with fast amplifier with sub-ns rise-time (Transient Current Technique)
- Laser beam width 8 µm FWHM under the chosen strip, fast (40 ps) and powerful laser
 - Caveat injecting charge under all strips effectively results in constant weighting (albeit not electric !) field





Electr

Electric Field Measurement

- Initial signal proportional to velocity sum at given detector depth
- Caveats for field extraction
 - Transfer function of electronics smears out signal, snapshot taken at ~600 ps
 - Problematic with heavy trapping
 - Electrons with v_{sat} hit electrode in 500 ps
 - Mobility depends on E
 - v saturates for E >> 1V/μm



 $I(t=0) = q \cdot v \cdot \vec{E}_w =$ $= N_{e-h} e_0 \cdot (v_e + v_h)/d =$ $= N_{e-h} e_0 \cdot (\mu_e + \mu_h) \cdot E(x)/d$





- Charge multiplication (CM) additional trouble for interpretation at large V
- Nice, but let's get quantitative !

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100 150 200 250 300 350

0 50

- can use $\int E(y)dy = \overline{E}d = V$ to pin down field scale Marko Mikuž: E, μ and τ in irrad. Si

- corrections from v(E) non-linearity small
- Use same scale for reverse bias!
- FW measurements up to 700 V
 - know E scale up to 2.33 V/ μ m

- can reveal v(E) dependence

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Absolute Field Measurement

- Solution: concurrent forward bias v_{sum} measurements
 - Ohmic behaviour with some linear (field) dependence
 - constant (positive) space charge



0.2

⊅ = 1e17

Forward Bias: 100-700



Proton Irradiations

- 5 sample pairs of ATL12 mini-strips irradiated at CERN PS during summer 2015
 - got 0.5, 1.0, 2.9, 11, 28e15 protons/cm²
 - NIEL hardness factor 0.62
 - thanks to CERN IRRAD team
- Covers HL-LHC tracker range well
- Samples back in September 15, 2 per fluence investigated by E-TCT for all fluences
 - concurrent forward and reverse bias measurements

Model with

For forward bias can extract v(E) up to a scale factor

Observe less saturation than predicted

 $v_{sum}(E) = \frac{\mu_{0,e}E}{1 + \frac{\mu_{0,e}E}{v_{e,sat}}} + \frac{\mu_{0,h}E}{1 + \frac{\mu_{0,h}E}{v_{h,s}}}$ keep saturation velocities at nominal values

- @-20°C ($v_{e,sat}$ = 107 µm/ns; $v_{h,sat}$ = 83 µm/ns)
- float (common) zero field mobility degradation
- fit v(E) for $\phi_n \ge 5 \times 10^{15}$ and $\phi_p \ge 3 \times 10^{15}$

n.b. FW profiles less uniform for lower fluences and for protons, but departures from average field still small







Mobility Considerations FW bias



Mobility Fits



- $-\mu_0$ degradation the only free parameter, scale fixed by $v_{sum,sat}$
- although E range limited, v_{sum,max} still > 1/3 of v_{sum,sat}





Mobility Results

Fit to v_e + v_h with common mobility degradation factor

- factor of 2 at $10^{16} n_{eq}/cm^2$
- factor of 6 at $10^{17} n_{eq}/cm^2$
- need 2x/6x higher E to saturate v !

Фn	μ _{0,sum}	Фр	μ _{0,sum}
[10 ¹⁵ n _{eq} /cm ²]	[cm²/Vs]	[10 ¹⁵ n _{eq} /cm ²]	[cm ² /Vs]
non-irr (model)	2680		
5	1661 ± 134	1.8	2165± 212
10	1238 ± 131	6.8	1319± 67
50	555 ± 32	17	750± 54
100	407 ± 40	T=-2	20°C



Mobility Analysis

• Fit mobility dependence on fluence with a power law

$$\mu_{0,sum}(\Phi) = C\Phi^{\prime}$$

- Fits perfectly with a ≈ -1/2 indicating a single scattering process in this fluence range
 - ~same *a* for neutrons and protons
- Below ~10¹⁵ n_{eq}/cm² the process gets obscured by acoustic phonon scattering
- At same equivalent fluence, mobility decrease ~20 % worse for protons
 - NIEL violation
- Is $a \approx -1/2$ accidental ?



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Velocity and Field Profiles

- Knowing v(E) can set scale to velocity profiles
 - assumption: same scale on FW and reverse bias
 - protons: for 5x10¹⁴ and 10¹⁵ use same scale, fixed by average field for 5x10¹⁴ at 1100 V (no good FW data)
- Invert *E(v)* to get electric field profiles
 - big errors when approaching v_{sat} i.e. at high E
 - exaggerated by CM in high field regions
 - v > v_{sat} not physical, but can be faked by CM



Velocity Profiles Neutrons





Field Profiles Neutrons











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Field Profiles Protons





Protons <-> Neutrons ~10¹⁶

Field profiles compared



 Protons with more "double junction", flatter field, less peaked at junction



Protons 2.8x10¹⁶ p/cm²

• Field profile, compared to 10¹⁶ neutrons





Looks more neutron-like, with deeper SCR



Trapping Considerations

• Extrapolation from low fluence data with $\beta_{e,h}(-20^{\circ}\text{C})=4.4,5.8\times10^{-16}\,\text{cm}^2/\text{ns}; 1/\tau=6\Phi$

Ф [1е15]	5	10	50	100
τ [ps]	400	200	40	20
<i>mfp@v_{sat}</i> [µm]	95	48	9.5	4.8
MPV [e ₀]	7600	3800	760	380
<i>MPV@</i> 1000 V	8900	5500	1800	1150
<i>ССD</i> _{1000 v} [µm]	110	70	23	14

- Measured data exceeds (by far) linear extrapolation of trapping
 - n.b.1: E^{3} V/µm by far not enough to saturate velocity - n.b.2: little sign of CM at highest fluence

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More Considerations

• More realistic: take v_{sum} at average $E = 3.3 \text{ V/}\mu\text{m}$

Ф [1е15]	5	10	50	100	Mobil y neutrons
<i>v_{sum}(3.3</i> V/μm)	137	126	90	77	1 100
<i>ССD</i> _{1000 V} [µm]	110	70	23	14	
<i>τ</i> ≈ <i>CCD</i> /v [ps]	800	560	260	180	00 Non-irradiated(model) 60 − − − − − − − − − − − − − − − − − − −
τ _{ext} [ps]	400	200	40	20	20

- Implies factor of 6-9 less trapping at highest fluences
 - lowest fluence still x2 from extrapolation
 - weak dependence on fluence as anticipated by "-1/6" power law
 - not good when large E variations (damped by v(E))
 - not good when CCD \approx thickness (less signal at same τ)



Exploiting TCT Waveforms

- Waveforms at y=100 μm, 800 V, 5x10¹⁶ and 10¹⁷
 - $E \approx 3 \text{ V/}\mu\text{m}$, CCD/2 implies signal within ~10 μm or <0.2 ns
 - the rest you see is the transfer function of the system
- Still distinct signals from the two fluences
 - treat 10¹⁷ waveform as transfer function of the system
 - convolute with $e^{-t/\tau}$ to match 5x10¹⁶ response
 - τ = 0.2 ns provides a good match
- In fact, measure $\Delta \tau$, as "transfer" already convoluted with $e^{-t/\tau(1e_{17})}$!
 - Should do proper Fourier analysis, on the way...





Δτ = 0.2 ns certainly best fit, 0.1 too narrow, 0.3 too broad
precision ~50 ps

Trapping – position dependence ?

- Waveforms plotted every 50 um in detector depth for reverse bias at 1000 V
- Forward bias in middle of detector added at 600 V
- Very little, if any, wf dependence on position observed
- Trapping not position (even not bias) dependent !?







Do's and Don'ts



- But if you have to spend millions, you better do
- What are the error bars associated to the measurements shown ?
- for p's we have 2 samples at each fluence
 - comparison should tell us a lot
- ...and it does !



- Preliminary, let's hope we find the cause...
- Hard to claim errors with such discrepancy
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Summary



- Velocity profiling performed for Si detectors irradiated
 - with neutrons from 10^{15} to 10^{17} n_{eq}/cm²
 - with protons from 5×10^{14} to 3×10^{16} p/cm²
- Velocity vs. electric field fluence impact observed and interpreted as reduction of zero field mobility
 - Zero field mobility follows power law with $a \approx -1/2$
 - Protons degrade mobility by ~20 % more
- Absolute velocities and field maps provided
 - With caveats at high electric fields
- Trapping estimates for very high neutron fluences
 - from charge collection
 - from waveforms
 - all estimates point to severe non-linearity of trapping with fluence
- To do:
 - CCE for protons
 - Reproducibility ?!
 - Sensible error estimates



Backup Slides



Result ?



- Victory ? Wrong... two effects
 - saturating v(E) -> less
 signal, effectively more
 trapping
 - charge multiplication -> more signal, less trapping
- Old story revisited, no handle on 1st few 10 microns where a lot can happen



-50 -1.0 0

350

200

y [um]

250

100

■ 200 ▲ 300 × 400

× 500

600
 700
 800

- 900 • 1000 = 1100



Another try

- Focus on cases with small and linear v(E) -> v(E) = v
 - 100 V at 5x10¹⁶ and 10¹⁷
 look promising flat field
 - also the integral of *E(x)* yields 63/100 and 76/100 V
- Can assume linear v(E) in whole detector
 - assume same ratio as for low fluences
 - less trapping compared to linear extrapolation by factors of 3.2 and 5.4



Φ	τ _e [ps]	τ _h [ps]
5e16	147	81
1e17	81	62